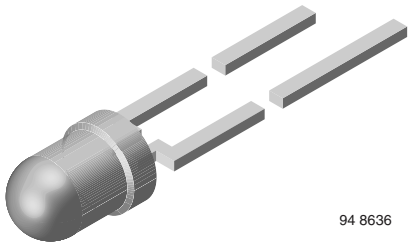
High Speed Infrared Emitting Diode, 850 nm, Surface Emitter Technology



FEATURES

- Package type: leaded
- Package form: T-1, clear epoxy
- Dimensions: Ø 3 mm
- Peak wavelength: λ_p = 850 nm
- High speed
- High radiant power
- High radiant intensity
- Angle of half intensity: φ = ± 18°
- Suitable for high pulse current operation
- Good spectral matching with CMOS cameras
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Pb-free

e2

RoHS COMPLIANT

GREEN (5-2008)**

Note

** Please see document “Vishay Material Category Policy”: www.vishay.com/doc?99902

DESCRIPTION

VSLY3850 is an infrared, 850 nm emitting diode based on GaAlAs surface emitter chip technology with extreme high radiant intensity, high optical power and high speed, molded in a clear, untinted T1 plastic package.

APPLICATIONS

- Infrared radiation source for operation with CMOS cameras
- High speed IR data transmission
- 3D TV application
- Light curtains

PRODUCT SUMMARY

COMPONENT	I_e (mW/sr)	φ (deg)	λ_p (nm)	t_r (ns)
VSLY3850	70	± 18	850	10

Note

- Test conditions see table “Basic Characteristics”

ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
VSLY3850	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1

Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	5	V
Forward current		I_F	100	mA
Peak forward current	t_p/T = 0.5, t_p = 100 µs	I_{FM}	200	mA
Surge forward current	t_p = 100 µs	I_{FSM}	1	A
Power dissipation		P_V	190	mW
Junction temperature		T_j	100	°C
Operating temperature range		T_{amb}	- 40 to + 85	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Soldering temperature	t ≤ 5 s, 2 mm from case	T_{sd}	260	°C
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R_{thJA}	300	K/W

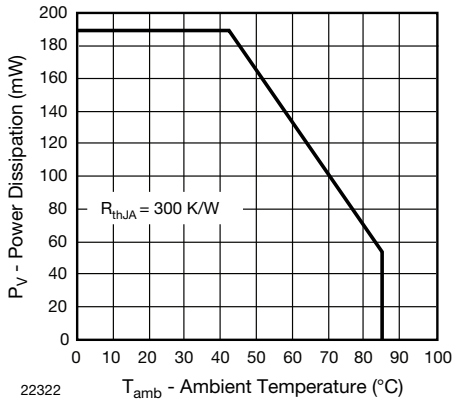


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

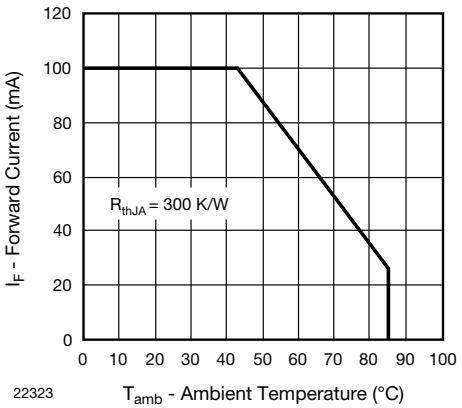


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Forward voltage	I_F = 100 mA, t_p = 20 ms	V_F		1.65	1.9	V
	I_F = 1 A, t_p = 100 µs	V_F		2.9		V
Temperature coefficient of V_F	I_F = 1 mA	TK_{VF}		- 1.45		mV/K
	I_F = 10 mA	TK_{VF}		- 1.25		mV/K
Reverse current		I_R	not designed for reverse operation			µA
Junction capacitance	V_R = 0 V, f = 1 MHz, E = 0 mW/cm^2	C_J		125		pF
Radiant intensity	I_F = 100 mA, t_p = 20 ms	I_e	35	70	105	mW/sr
	I_F = 1 A, t_p = 100 µs	I_e		600		mW/sr
Radiant power	I_F = 100 mA, t_p = 20 ms	ϕe		55		mW
Temperature coefficient of radiant power	I_F = 1 mA	$TK_{\varphi e}$		- 0.35		%/K
Angle of half intensity		φ		± 18		deg
Peak wavelength	I_F = 30 mA	λ_p	840	850	870	nm
Spectral bandwidth	I_F = 30 mA	$\Delta\lambda$		30		nm
Temperature coefficient of λ_p	I_F = 30 mA	$TK_{\lambda p}$		0.25		nm
Rise time	I_F = 100 mA, 20 % to 80 %	t_r		10		ns
Fall time	I_F = 100 mA, 20 % to 80 %	t_f		10		ns

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

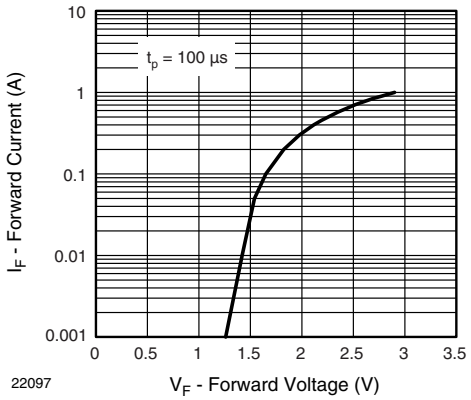


Fig. 3 - Forward Current vs. Forward Voltage

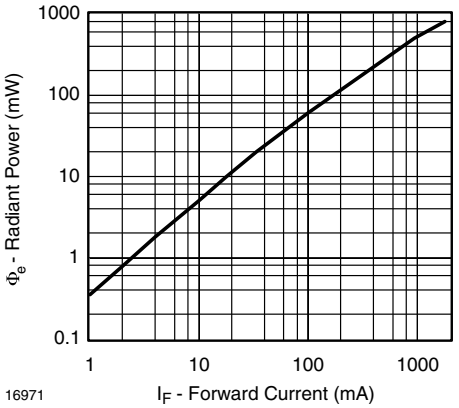


Fig. 6 - Radiant Power vs. Forward Current

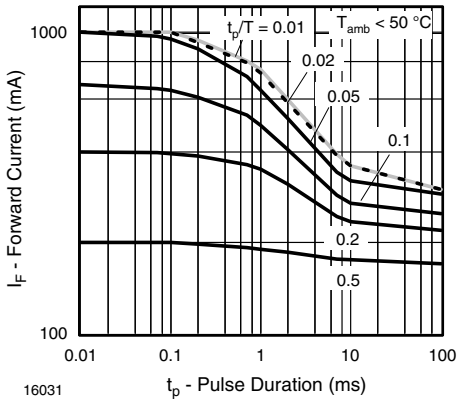


Fig. 4 - Pulse Forward Current vs. Pulse Duration

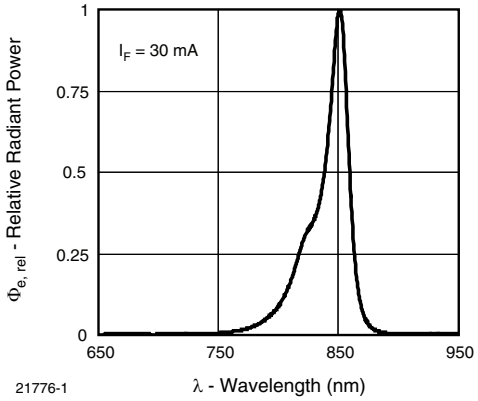


Fig. 7 - Relative Radiant Power vs. Wavelength

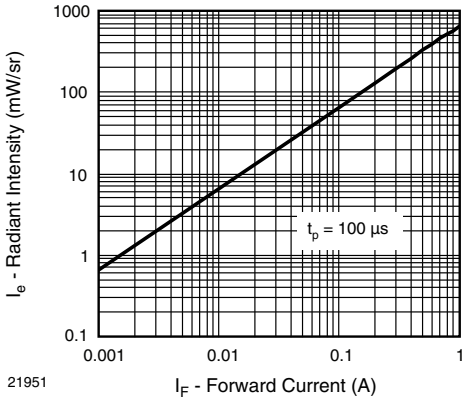


Fig. 5 - Radiant Intensity vs. Forward Current

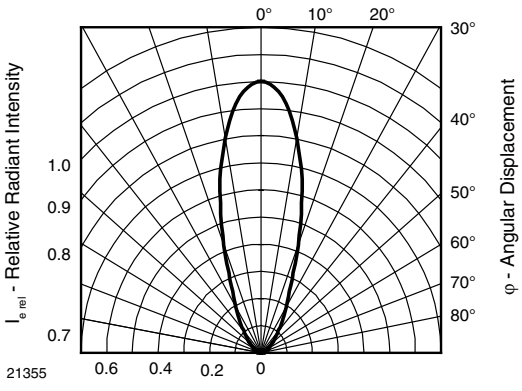
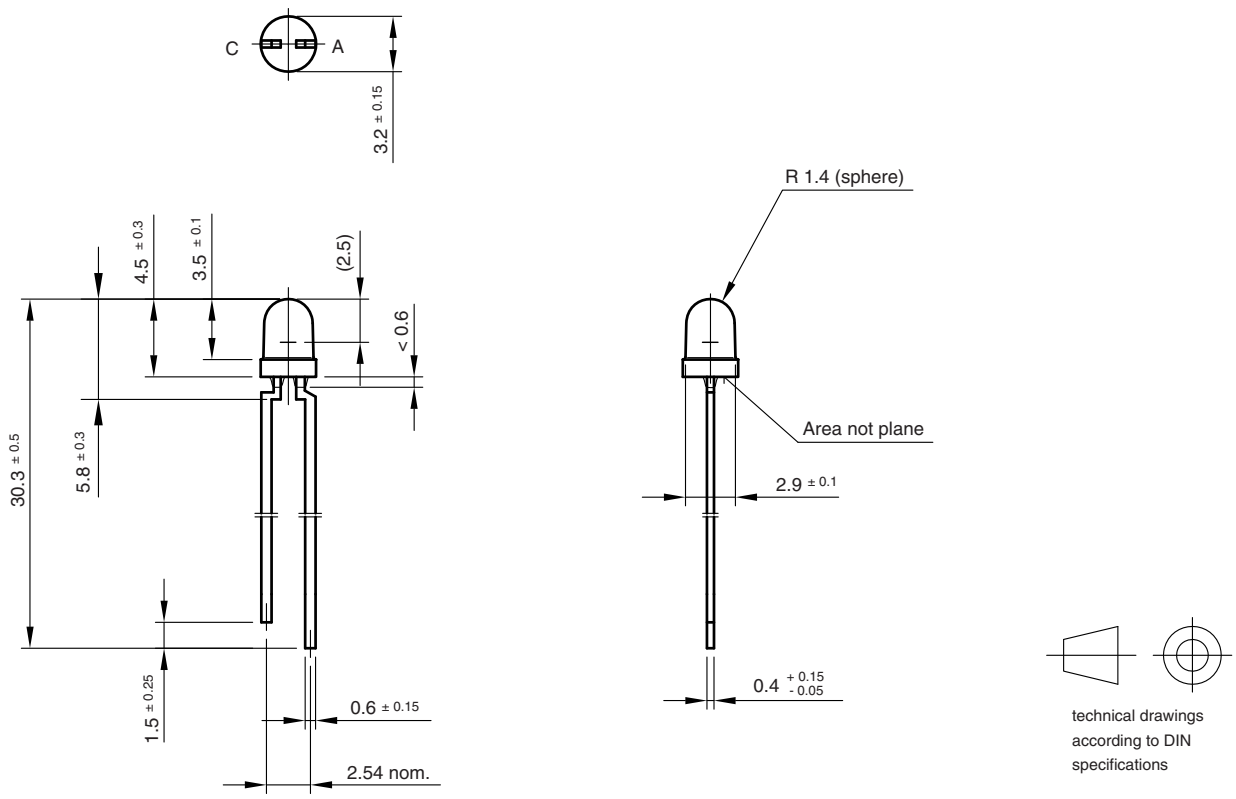


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters



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